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With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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MPSH34

NPN General Purpose Amplifier • This device is designed for common-emitter low noise

- This device is designed for common-emitter low noise amplifier and mixer applications with collector currents in the 100mA to 20mA range to 300MHz, and low frequency drift common-base VHF oscillator applications with high output levels for driving FET mixers.
- · Sourced from process 47.
- See MPSH11 for characteristics.



1. Base 2. Emitter 3. Collector

Absolute Maximum Ratings T_a =25°C unless otherwise noted

Symbol	Parameter	Value	Units
V_{CEO}	Collector-Emitter Voltage	40	V
V _{CBO}	Collector-Base Voltage	40	V
V _{EBO}	Emitter-Base Voltage	4.0	V
I _C	Collector current - Continuous	50	mA
T _J , T _{stg}	Junction and Storage Temperature	-55 ~ +150	°C

Electrical Characteristics T_a=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Max.	Units
Off Charact	eristics			-	
V _{(BR)CEO}	Collector-Emitter Sustaining Voltage *	$I_C = 1.0 \text{mA}, I_B = 0$	40		V
V _{(BR)CBO}	Collector-Base Breakdown Voltage	$I_C = 100 \mu A, I_E = 0$	40		
V _{(BR)EBO}	Emitter-Base Breakdown Voltage	$I_E = 10\mu A, I_C = 0$	4.0		VV
I _{CBO}	Collector Cutoff Current	V _{CB} = 30V, I _E = 0		50	nA
On Characte	eristics			•	
h _{FE}	DC Current Gain	$V_{CE} = 2.0V, I_{C} = 20mA$ $V_{CE} = 15V, I_{C} = 7.0mA$	15 40		
V _{CE(sat)}	Collector-Emitter Saturation Voltage	$I_C = 7.0 \text{mA}, I_B = 2.0 \text{mA}$		0.5	V
V _{BE(on)}	Base-Emitter On Voltage	V _{CE} = 15V, I _C = 7.0mA		0.95	V
	I Characteristics				•
f _T	Current Gain Bandwidth Product	I _C =15mA, V _{CE} = 15V, f = 100MHz	500		MHz
C _{cb}	Collector-Base Capacitance	V _{CB} = 10V, I _E = 0, f = 1.0MHz		0.32	pF

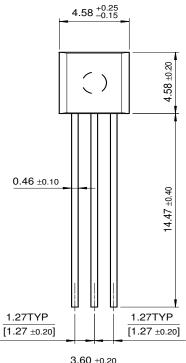
^{*} Pulse Test: Pulse Width ≤ 300μs, Duty Cycle ≤ 2.0%

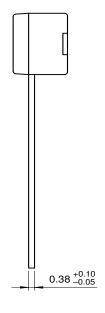
Thermal Characteristics TA=25°C unless otherwise noted

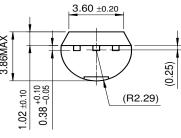
Symbol	Parameter	Max.	Units
P _D	Total Device Dissipation	625	mW
	Derate above 25°C	5.0	mW/°C
$R_{\theta JC}$	Thermal Resistance, Junction to Case	83.3	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	200	°C/W

Package Dimensions

TO-92







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Definition of Terms

Datasheet Identification	Product Status	Definition
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